

View Online at <https://aerobasegroup.com/nsn/5961-01-252-5902>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.170 inches all semiconductor device diode

Terminal Length:

0.973 inches all semiconductor device diode

Overall Diameter:

0.073 inches all semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pin all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

3 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Features Provided:

Burn in and electrostatic sensitive

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

100.0 reverse voltage, dc all semiconductor device diode

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius ambient air all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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